

Supporting Information

Large area growth of SnS₂/Graphene on cellulose paper as a flexible broadband photodetector and investigating the band structure through First Principle Calculations

Venkatarao Selamneni¹, Sayan Kanungo¹, and Parikshit Sahatiya^{1*}

¹Department of Electrical and Electronics Engineering, Birla Institute of Technology and Science Pilani Hyderabad Campus, Hyderabad 500078, India

*Corresponding author: E-mail: parikshit@hyderabad.bits-pilani.ac.in; Telephone: 040-66303617

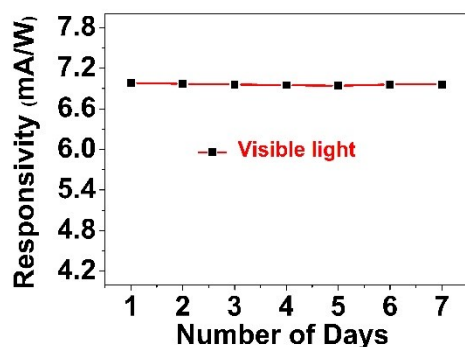


Figure S1: Graph showing the responsivity vs. number of days, indicating the stability of the device.

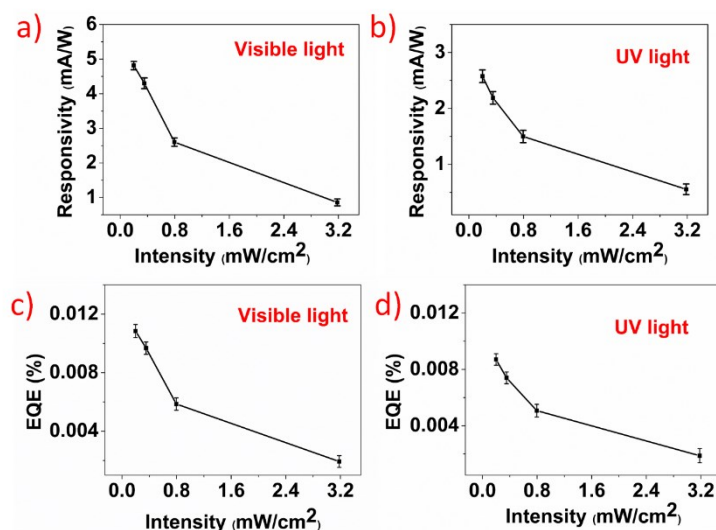


Figure S2: a, b) Responsivity v/s intensity under Visible and UV illumination, c,d) EQE v/s intensity under visible and visible illumination of SnS₂ grown on cellulose paper

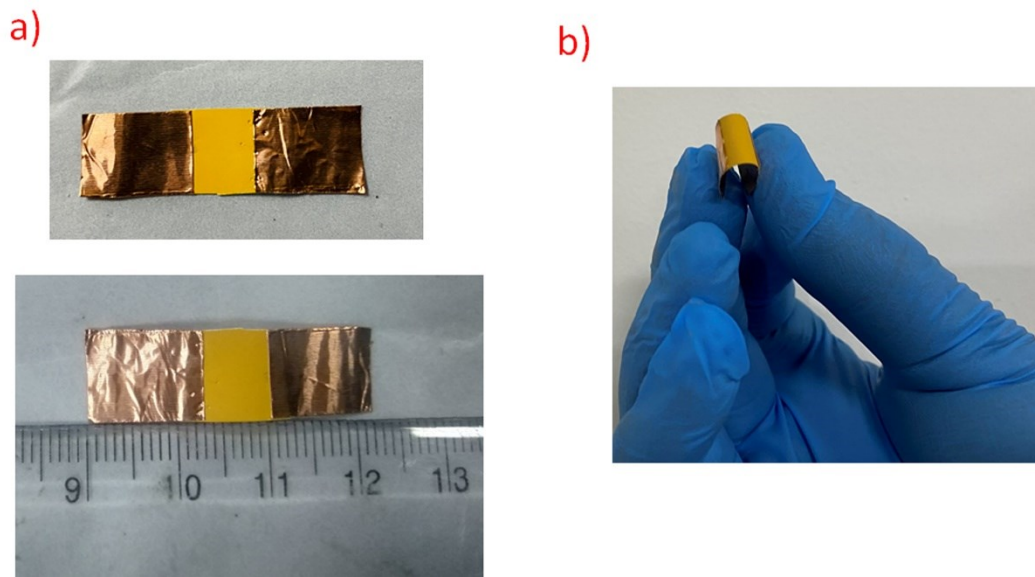


Figure S3: a) Digital image of the fabricated SnS₂/Gr based device with an active area of 7 mm x 7 mm b) Digital image of the fabricated device in bending state.